

BV _{DSS}	R _{DS(ON)}	I _D
55 V	1.6 Ω	360 mA

SOT-23

Features

- 55V, 0.36A, $R_{DS(ON)}$ =1.6 Ω @ V_{GS} =10V
- ESD Protected
- · Fast switching
- · Green Device Available

Applications

- Case : SOT-23
- Load Switch
- · Hand-Held Instruments

Absolute Maximum Ratings T _A =25°C unless otherwise noted						
Symbol	Parameter	Rating	Units			
V _{DS}	Drain-Source Voltage	55	V			
V_{GS}	Gate-Source Voltage	±20	V			
I _D	Drain Current - Continuous	360	mA			
I _{DM}	Drain Current - Pulsed	2000	mA			
P _D	Total Power Dissipation (T _A =25°C) (NOTE 1)	350	mW			
T _J	Operating Junction Temperature Range	-50 to 150	°C			
T _{STG}	Storage Temperature Range	-50 to 150	°C			
Marking Code		E38				

NOTES:

1.1*MRP FR-4 PC board,2oz.

Thermal Characteristics					
Symbol	Parameter	Тур.	Max	Unit	
$R_{\theta JA}$	Thermal Resistance Junction to Ambient		357	°C/W	





Electrical Characteristics (T_J=25°C, unless otherwise noted)

Off Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =10uA	55			V
I _{DSS}	Drain-Source Leakage Current	V_{DS} =55V , V_{GS} =0V			1	uA
I _{GSS}	Gate-Source Leakage Current	V_{GS} =±20V , V_{DS} =0V			±10	uA

On Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
R _{DS(ON)}	Static Drain-Source On-Resistance	V_{GS} =2.5V , I_D =100mA		2.6	4.5	
		V_{GS} =4.5V , I_D =200mA		1.5	2.5	Ω
		V_{GS} =10V , I_D =500mA		1.3	1.6	
$V_{GS(th)}$	Gate Threshold Voltage	V _{GS} =V _{DS} , I _D =250uA	0.8		1.5	V
gfs	Forward Transconductance	V _{DS} =10V , I _D =250mA	300			mS

Dynamic and switching Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Q_g	Total Gate Charge	V_{DS} =15V , V_{GS} =5V , I_{D} =200mA			1	nC
$T_{d(on)}$	Delay Turn-On Time	V_{DD} =30V , R_L =150 Ω , V_{GS} =10V , R_G =10 Ω , I_D =200mA		1.3		ne
$T_{d(off)}$	Delay Turn-Off Time			5.5		ns
C _{iss}	Input Capacitance	V _{DS} =25V , V _{GS} =0V , F=1MHz			50	
C_{oss}	Output Capacitance			7		pF
C _{rss}	Reverse Transfer Capacitance			4		

Drain-Source Diode Characteristics and Ratings

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Is	Continuous Source Current	V _G =V _D =0V, Force Current			500	mA
V_{SD}	Diode Forward Voltage	V _{GS} =0V , I _S =500mA		0.94	1.2	V
t _{rr}	Reverse Recovery Time	V_{GS} =0V, V_{DD} =30V, I_{S} =1A,		14.4		nS
Q_{rr}	Reverse Recovery Charge	dls/dt=100A/us		5.8		nC





Characteristics Curves

FIG. 1-Output Characteristic

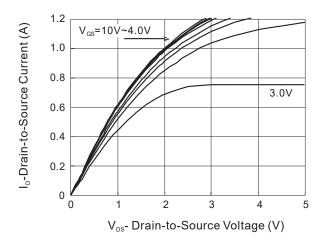


FIG. 2-Transfer Characteristic

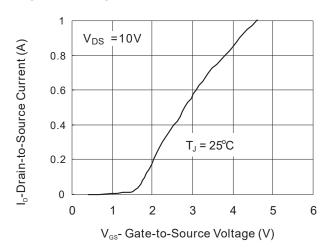


FIG. 3-On-Resistance vs Drain Current

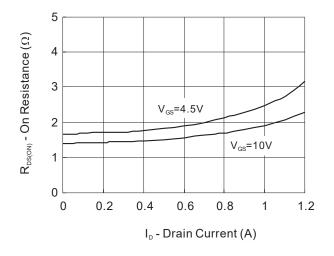


FIG. 4-On-Resistance vs Gate to Source Voltage

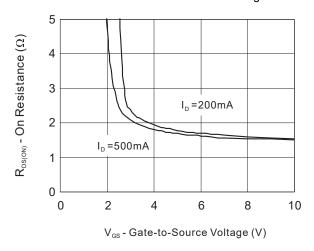


FIG. 5-On-Resistance vs Junction Temperature

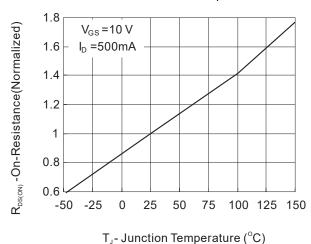
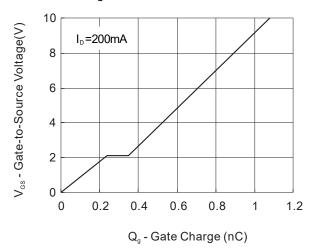


FIG. 6-Gate Charge Waveform







Characteristics Curves

FIG. 7-Source-Drain Diode Forward Voltage

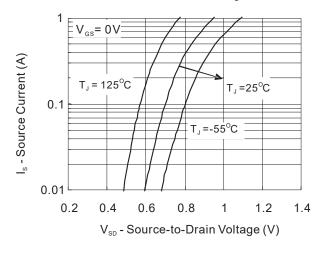


FIG. 8-Threshold Voltage vs Temperature

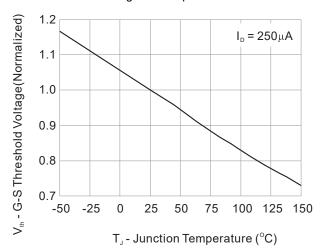


FIG. 9-Breakdown Voltage vs Junction Temperature

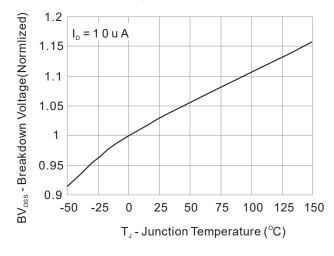
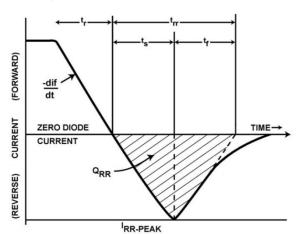
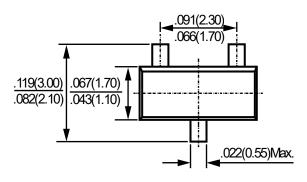
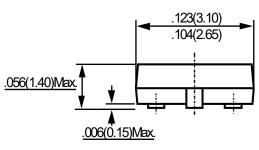


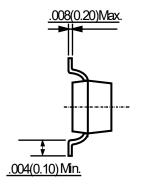
FIG. 10-QRR and TRR Waveform definitions



Package Outline Dimensions







SOT-23Dimensions in inches and (millimeters)





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